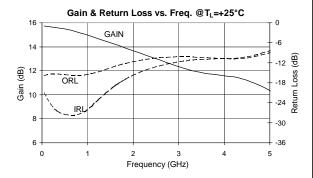


Product Description

Stanford Microdevices' SGA-6389 is a high performance SiGe Heterojunction Bipolar Transistor MMIC Amplifier. A Darlington configuration featuring 1 micron emitters provides high $F_{\scriptscriptstyle T}$ and excellent thermal perfomance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. At 850 Mhz and 80mA , the SGA-6389 typically provides +35.2 dBm output IP3, 15.7 dB of gain, and +20.2 dBm of 1dB compressed power using a single positive voltage supply. Only 2 DC-blocking capacitors, a bias resistor and an optional RF choke are required for operation.



SGA-6389

DC-4000 MHz, Cascadable SiGe HBT MMIC Amplifier



Product Features

- · High Gain: 14.0 dB at 1950 MHz
- Cascadable 50ohm
- Patented InGaP Technology
- Operates From Single Supply
- Low Thermal Resistance Package

Applications

• Cellular, PCS, CDPD

= 50 Ohms

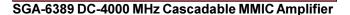
- Wireless Data, SONET
- Satellite

| Symbol | Parameter | Units | Frequency | Min. | Тур. | Max. |
|------------------|--|----------------|---------------------------------|------------|----------------------|------|
| G | Small Signal Gain | dB dB dB | 850 MHz 1950 MHz 2400 MHz | 14.1 | 15.7 14.0 13.3 | 17.3 |
| P _{1dB} | Output Power at 1dB Compression | dBm dBm | 850 MHz 1950 MHz | | 20.2 18.9 | |
| OIP ₃ | Output Third Order Intercept Point (Power out per tone = 0dBm) | dBm dBm | 850 MHz 1950 MHz | | 35.2 32.6 | |
| Bandwidth | Determined by Return Loss (<-10dB) | MHz | | | 4000 | |
| IRL | Input Return Loss | dB | 1950 MHz | | 16.0 | |
| ORL | Output Return Loss | dB | 1950 MHz | | 11.9 | |
| NF | Noise Figure | dB | 1950 MHz | | 4.2 | |
| V _D | Device Voltage | V | | 4.5 | 4.9 | 5.3 |
| R _{Th} | Thermal Resistance | | | | 97 | |
| | V = 8v L = 80mA Tvp | IP3 Tone | Spacing = 1 MHz | Pout ner t | tone = 0 dBr | n |

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=39 ohms

Test Conditions:





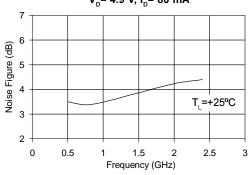
Typical RF Performance at Key Operating Frequencies

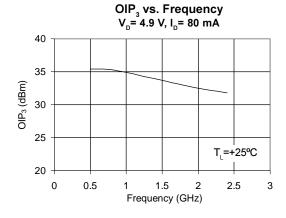
| | | | Frequency (MHz) | | | | | |
|------------------|------------------------------------|------|-----------------|------|------|------|------|------|
| Symbol | Parameter | Unit | 100 | 500 | 850 | 1950 | 2400 | 3500 |
| G | Small Signal Gain | dB | | 15.5 | 15.7 | 14.0 | 13.3 | |
| OIP ₃ | Output Third Order Intercept Point | dBm | | 35.4 | 35.2 | 32.6 | 31.8 | |
| P_{1dB} | Output Power at 1dB Compression | dBm | | 20.4 | 20.2 | 18.9 | 18.1 | |
| IRL | Input Return Loss | dB | 22.3 | 27.5 | 27.4 | 16.0 | 13.7 | 11.0 |
| ORL | Output Return Loss | dB | 14.7 | 14.5 | 14.8 | 11.9 | 10.8 | 10.4 |
| S ₁₂ | Reverse Isolation | dB | 20.4 | 20.2 | 20.3 | 20.1 | 19.7 | 18.2 |
| NF | Noise Figure | dB | | 3.5 | 3.4 | 4.2 | 4.4 | |

Test Conditions:

 $V_s = 8v$ $R_{BAS} = 39 \text{ ohms}$ I_D = 80mA Typ. Τ. = 25°C IP3 Tone Spacing = 1 MHz, Pout per tone = 0 dBm $Z_s = Z_t = 50$ Ohms

Noise Figure vs. Frequency $V_D = 4.9 \text{ V}, I_D = 80 \text{ mA}$



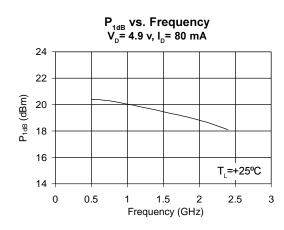


Absolute Maximum Ratings

| Parameter | Absolute Limit |
|---|----------------|
| Max. Device Current (I _D) | 160 mA |
| Max. Device Voltage (V _D) | 7 V |
| Max. RF Input Power | +16 dBm |
| Max. Junction Temp. (T _J) | +150°C |
| Operating Temp. Range (T _L) | -40°C to +85°C |
| Max. Storage Temp. | +150°C |

Operation of this device beyond any one of these limits may cause permanent damage.

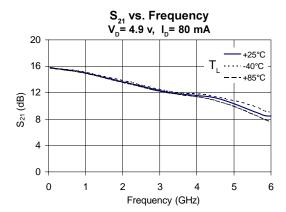
Bias Conditions should also satisfy the following expression: I_DV_D (max) < $(T_A - T_A)/R_{HD}$

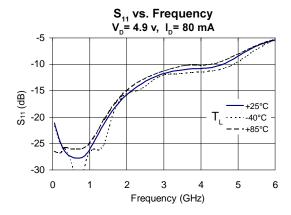


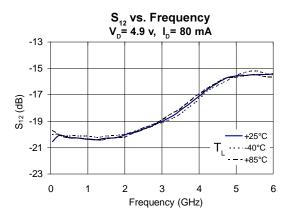
Phone: (800) SMI-MMIC

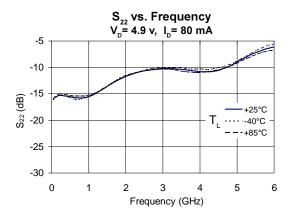


SGA-6389 DC-4000 MHz Cascadable MMIC Amplifier



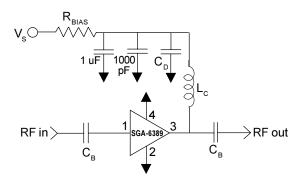


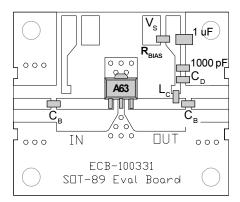






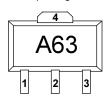
SGA-6389 Basic Application Circuit





Part Identification Marking

The part will be marked with an "A63" designator on the top surface of the package.



For package dimensions, refer to outline drawing at www.stanfordmicro.com



Caution: ESD sensitive

Appropriate precautions in handling, packaging and testing devices must be observed.

Application Circuit Element Values

| Reference | | Frequency (Mhz) | | | | | | |
|----------------|--------|-----------------|-------|-------|-------|--|--|--|
| Designator | 500 | 850 | 1950 | 2400 | 3500 | | | |
| C _B | 220 pF | 100 pF | 68 pF | 56 pF | 39 pF | | | |
| C _D | 100 pF | 68 pF | 22 pF | 22 pF | 15 pF | | | |
| L _c | 68 nH | 33 nH | 22 nH | 18 nH | 15 nH | | | |

| Recommended Bias Resistor Values for I _D =80mA | | | | |
|--|------|------|------|------|
| Supply Voltage(Vs) | 7.5V | 8V | 10V | 12V |
| R _{BIAS} | 33 Ω | 39 Ω | 62 Ω | 91 Ω |
| Note: R _{BIAS} provides DC bias stability over temperature. | | | | |

Mounting Instructions

- Solder the copper pad on the backside of the device package to the ground plane.
- 2. Use a large ground pad area with many plated through-holes as shown.
- We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.

| Pin# | Function | Description |
|------|-----------------|---|
| 1 | RF IN | RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation. |
| 2 | GND | Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible. |
| 3 | RF OUT/ BIAS | RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation. |
| 4 | GND | Sames as Pin 2 |

Part Number Ordering Information

| Part Number | Reel Size | Devices/Reel |
|-------------|-----------|--------------|
| SGA-6389 | 7" | 1000 |